

FET Input Analog Front End with ADC Driver

ADA4350

FEATURES

Low noise, low input bias current FET input amplifier Very low input bias current: ±0.25 pA typical at 25°C Low input voltage noise 92 nV/√Hz typical at 10 Hz at 5 V 5 nV/√Hz typical at 100 kHz at ±5 V Gain bandwidth product: 175 MHz Input capacitance 3 pF typical, differential mode 2 pF typical, common mode Integrated gain switching Sampling and feedback switch off leakage: ±0.5 pA typical Worst case ton/toff times: 105 ns typical/65 ns typical Integrated analog-to-digital converter (ADC) driver Differential mode and single-ended mode Adjustable output common-mode voltage -5 V to +3.8 V typical for ±5 V supply Wide output voltage swing: ±4.8 V minimum for ±5 V supply Linear output current: 18 mA rms typical for ±5 V supply SPI or parallel switch control of all functions Wide operating range: 3.3 V to 12 V Quiescent current: 8.5 mA typical (±5 V full system)

APPLICATIONS

Current to voltage (I to V) conversions Photodiode preamplifiers Chemical analyzers Mass spectrometry Molecular spectroscopy Laser/LED receivers Data acquisition systems

GENERAL DESCRIPTION

The ADA4350 is an analog front end for photodetectors or other sensors whose output produces a current proportional to the sensed parameter or voltage input applications where the system requires the user to select between very precise gain levels to maximize the dynamic range.

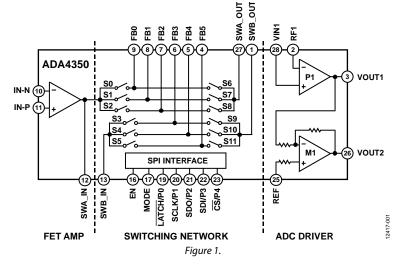
The ADA4350 integrates a FET input amplifier, a switching network, and an ADC driver with all functions controllable via a serial peripheral interface (SPI) or parallel control logic into a single IC. The FET input amplifier has very low voltage noise and current noise making it an excellent choice to work with a wide range of photodetectors, sensors, or precision data acquisition systems.

Its switching network allows the user individual selection of up to six different, externally configurable feedback networks; by using external components for the feedback network, the user can more easily match the system to their desired photodetector or sensor capacitance. This feature also allows the use of low thermal drift resistors, if required.

The design of the switches minimizes error sources so that they add virtually no error in the signal path. The output driver can be used in either single-ended or a differential mode and is ideal for driving the input of an ADC.

The ADA4350 can operate from a single +3.3 V supply or a dual ± 5 V supply, offering user flexibility when choosing the polarity of the detector. It is available in a Pb-free, 28-lead TSSOP package and is specified to operate over the -40°C to +85°C temperature range.

Multifunction pin names may be referenced by their relevant function only.



FUNCTIONAL BLOCK DIAGRAM

Rev. B

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Evaluation Kits

ADA4350 Evaluation Board

Documentation 🖵

Data Sheet

• ADA4350: FET Input Analog Front End With ADC Driver Data Sheet

User Guides

- UG-655: Evaluating the ADA4350, a FET Input Analog Front End With ADC Driver Offered in a 28-Lead 9.8 mm \times 6.4 mm TSSOP

Tools and Simulations

ADA4350 SPICE Macro-Model

Reference Materials

Press

· Integrated Analog Front-end Simplifies Sensor Interfaces

Design Resources

- ADA4350 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- · Symbols and Footprints

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TABLE OF CONTENTS

| Features |
|---|
| Applications1 |
| General Description 1 |
| Functional Block Diagram 1 |
| Revision History 2 |
| Specifications |
| ±5 V Full System |
| ±5 V FET Input Amplifier |
| ±5 V Internal Switching Network and Digital Pins |
| ±5 V ADC Driver |
| 5 V Full System 8 |
| 5 V FET Input Amplifier9 |
| 5 V Internal Switching Network and Digital Pins10 |
| 5 V ADC Driver11 |
| Timing Specifications13 |
| Absolute Maximum Ratings15 |
| Thermal Resistance |
| Maximum Power Dissipation15 |
| ESD Caution15 |
| Pin Configuration and Function Descriptions |

REVISION HISTORY

| 3/16—Rev. A to Rev. B | |
|-----------------------|--|
| Change to Table 15 | |

12/15—Rev. 0 to Rev. A

| Changes to Table 1 | 3 |
|---|----|
| Changes to Table 5 | 8 |
| Deleted Figure 4; Renumbered Sequentially | 14 |
| Changes to Table 10 | 15 |
| Changes to Table 14 | |

4/15—Revision 0: Initial Version

| Typical Performance Characterisitics | 17 |
|--|----|
| Full System | 17 |
| FET Input Amplifier | 19 |
| ADC Driver | 22 |
| Test Circuits | 26 |
| Theory of Operation | 27 |
| Kelvin Switching Techniques | 27 |
| Applications Information | 28 |
| Configuring the ADA4350 | 28 |
| Selecting the Transimpedance Gain Paths Manually or Through the Parallel Interface | 28 |
| Selecting the Transimpedance Gain Paths Through the SPI Interface (Serial Mode) | 28 |
| SPICE Model | 30 |
| Transimpedance Amplifier Design Theory | 32 |
| Transimpedance Gain Amplifier Performance | 34 |
| The Effect of Low Feedback Resistor $R_{\mbox{\tiny Fx}}$ | 35 |
| Using The T Network to Implement Large Feedback Resistor Values | 36 |
| Outline Dimensions | 37 |
| Ordering Guide | 37 |
| | |

SPECIFICATIONS ±5 V FULL SYSTEM

 $T_A = 25^{\circ}$ C, $+V_S = +5$ V, $-V_S = -5$ V, $R_L = 1$ k Ω differential, unless otherwise specified.

| Parameter | Test Conditions/Comments | Min | Тур | Max | Unit |
|--|---|------|----------|------|--------|
| DYNAMIC PERFORMANCE | | | | | |
| –3 dB Bandwidth | Gain (G) = -5, V _{OUT} = 200 mV p-p | | 20 | | MHz |
| | $G = -5$, $V_{OUT} = 2 V p - p$ | | 12 | | MHz |
| Slew Rate | V _{OUT} = 2 V step, 10% to 90% | | 60 | | V/µs |
| HARMONIC PERFORMANCE | | | | | |
| Harmonic Distortion (HD2/HD3) | $G = -5$, $f_C = 100 \text{ kHz}$ | | -95/-104 | | dBc |
| | $G = -5$, $f_C = 1 MHz$ | | -77/-78 | | dBc |
| DC PERFORMANCE | | | | | |
| Input Bias Current | At 25°C | | ±0.25 | ±1 | pА |
| | At 85°C | | ±8 | ±25 | pА |
| INPUT CHARACTERISTICS | | | | | |
| Input Resistance | Common mode | | 100 | | GΩ |
| Input Capacitance | Common mode | | 2 | | pF |
| | Differential mode | | 3 | | pF |
| Input Common-Mode Voltage Range | Common-mode rejection ratio (CMRR) > 80 dB | -4.5 | | +3.8 | V |
| | CMRR > 68 dB | -5 | | +3.9 | V |
| Common-Mode Rejection | $V_{CM} = \pm 3.0 \text{ V}$ | 92 | 104 | | dB |
| OUTPUT CHARACTERISTICS | | | | | |
| Linear Output Current | $V_{OUT} = 4 V p-p, 60 dB spurious-free dynamic range (SFDR)$ | | 18 | | mA rms |
| Short-Circuit Current | Sinking/sourcing | | 43/76 | | mA |
| Settling Time to 0.1% | $G = -5$, $V_{OUT} = 2 V$ step | | 100 | | ns |
| ANALOG POWER SUPPLY (+V _s , -V _s) | | | | | |
| Operating Range | | 3.3 | | 12 | V |
| Quiescent Current | Enabled | | 8.5 | 10 | mA |
| | M1 disabled (see Figure 1) | | 7 | | mA |
| | All disabled | | 2 | | μΑ |
| Positive Power Supply Rejection Ratio | | | 90 | | dB |
| Negative Power Supply Rejection Ratio | | | 85 | | dB |
| DIGITAL SUPPLIES | DVDD, DGND | | | | |
| Digital Supply Range | | 3.3 | | 5.5 | V |
| Quiescent Current | Enabled | | 50 | | μΑ |
| | Disabled | | 0.6 | | μA |
| +Vs to DGND Head Room | | | ≥3.3 | | V |

±5 V FET INPUT AMPLIFIER

 $T_{\rm A}$ = 25°C, +V_{\rm S} = +5 V, -V_{\rm S} = -5 V, $R_{\rm L}$ = 1 kΩ, unless otherwise specified.

Table 2.

| Parameter | Test Conditions/Comments | Min | Тур | Max | Unit |
|---------------------------------------|--|--------------|----------------|------|--------|
| DYNAMIC PERFORMANCE | | | | | |
| –3 dB Bandwidth | G = -5, V _{OUT} = 100 mV p-p | | 26 | | MHz |
| | G = -5, V _{OUT} = 2 V p-p | | 24 | | MHz |
| Gain Bandwidth Product | | | 175 | | MHz |
| Slew Rate | V _{OUT} = 2 V step, 10% to 90% | | 100 | | V/µs |
| Settling Time to 0.1% | $G = -5$, $V_{OUT} = 2V$ step | | 28 | | ns |
| NOISE/HARMONIC PERFORMANCE | | | | | |
| Harmonic Distortion (HD2/HD3) | f = 100 kHz, V _{OUT} = 2 V p-p, G = -5 | | -106/-114 | | dBc |
| | f = 1 MHz, V _{OUT} = 2 V p-p, G = -5 | | -83/-93 | | dBc |
| Input Voltage Noise | f = 10 Hz | | 85 | | nV/√Hz |
| | f = 100 kHz | | 5 | | nV/√Hz |
| DC PERFORMANCE | | | | | |
| Input Offset Voltage | | | 15 | 80 | μV |
| Input Offset Voltage Drift | From –40°C to +85°C | | 0.1 | 1.6 | µV/°C |
| | From 25°C to 85°C | | 0.1 | 1.0 | µV/°C |
| Input Bias Current | At 25°C | | ±0.25 | ±1 | pА |
| | At 85°C | | ±8 | ±25 | pА |
| Input Bias Offset Current | At 25°C | | ±0.1 | ±0.8 | pА |
| | At 85°C | | ±0.5 | | pА |
| Open-Loop Gain | $V_{OUT} = \pm 2 V$ | 106 | 115 | | dB |
| INPUT CHARACTERISTICS | | | | | |
| Input Resistance | Common mode | | 100 | | GΩ |
| Input Capacitance | Common mode | | 2 | | pF |
| | Differential mode | | 3 | | pF |
| Input Common-Mode Voltage Range | CMRR > 80 dB | -4.5 | | +3.8 | V |
| | CMRR > 68 dB | -5 | | +3.9 | V |
| Common-Mode Rejection Ratio | $V_{CM} = \pm 3 V$ | 92 | 115 | | V |
| OUTPUT CHARACTERISTICS | | | | | |
| Output Overdrive Recovery Time | $V_{OUT} = V_S \pm 10\%$ | | 60 | | ns |
| Output Voltage Swing | $G = +21$, $R_F = 1 \text{ k}\Omega$, R_L open measured at FBx | -3.6 to +3.9 | -4.05 to +4.07 | | V |
| | $G = +21$, $R_F = 100 \text{ k}\Omega$, R_L open measured at FBx | -4.7 to +4.8 | -4.9 to +4.86 | | V |
| Linear Output Current | V _{OUT} = 2 V p-p, 60 dB SFDR | | 18 | | mA rms |
| Short-Circuit Current | Sinking/sourcing | | 41/45 | | mA |
| POWER SUPPLY | | | | | |
| Operating Range | | 3.3 | | 12 | V |
| Positive Power Supply Rejection Ratio | | 90 | 109 | | dB |
| Negative Power Supply Rejection Ratio | | 90 | 109 | | dB |

± 5 V INTERNAL SWITCHING NETWORK AND DIGITAL PINS

 $T_A = 25^{\circ}C$, $+V_S = +5 V$, $-V_S = -5 V$, unless otherwise specified. See Figure 1 for feedback and sampling switches notation.

| Parameter | Symbol | Test Conditions/Comments | Min | Тур | Max | Unit |
|---|---------------------|---|-----|------|------|---------|
| FEEDBACK/SAMPLE ANALOG SWITCH | | | | | | |
| Analog Signal Range | | | -5 | | +5 | V |
| Switch On-Resistance | | | | | | |
| Feedback | Ron, FB | For S0 to S2, $V_{CM} = 0 V$ | | 149 | 196 | Ω |
| | | $T_A = 85^{\circ}C$ | | 195 | | Ω |
| | | For S3 to S5, $V_{CM} = 0 V$ | | 149 | 196 | Ω |
| | | $T_A = 85^{\circ}C$ | | 195 | | Ω |
| Sampling | Ron, s | For S6 to S8, $V_{CM} = 0 V$ | | 297 | 356 | Ω |
| | | $T_A = 85^{\circ}C$ | | 390 | | Ω |
| | | For S9 to S11, $V_{CM} = 0 V$ | | 297 | 356 | Ω |
| | | $T_A = 85^{\circ}C$ | | 388 | | Ω |
| On-Resistance Match Between Channels | | | | | | |
| Feedback Resistance | $\Delta R_{ON, FB}$ | $V_{CM} = 0 V$ | | 2 | 15 | Ω |
| Sampling Resistance | $\Delta R_{ON,S}$ | $V_{CM} = 0 V$ | | 2 | 14 | Ω |
| SWITCH LEAKAGE CURRENTS | | | | | | |
| Sampling and Feedback Switch Off Leakage | Is (OFF) | | | ±0.5 | ±1.7 | pА |
| | - () | $T_A = 85^{\circ}C$ | | ±40 | ±120 | рА |
| DYNAMIC CHARACTERISTICS | | | | | | |
| Power-On Time | ton | DVDD = 5 V | | 76 | | ns |
| | | DVDD = 3.3 V | | 80 | | ns |
| Power-Off Time | toff | DVDD = 5V | | 86 | | ns |
| | | DVDD = 3.3 V | | 90 | | ns |
| Off Isolation | | $R_L = 50 \Omega$, $f = 1 MHz$ | | | | |
| Feedback Switches | | | | -92 | | dB |
| Sampling Switches | | | | -118 | | dB |
| Channel to Channel Crosstalk | | $R_L = 50 \Omega$, $f = 1 MHz$ | | -86 | | dB |
| Worst Case Switch Feedback Capacitance (Switch Off) | | | | 0.1 | | pF |
| THRESHOLD VOLTAGES FOR DIGITAL INPUT PINS | | EN, MODE, DGND, LATCH/PO, | | | | р. |
| | | SCLK/P1, SDO/P2, SDI/P3, CS/P4 ¹ | | | | |
| Input High Voltage | VIH | DVDD = 5V | 2.0 | | | v |
| input righ voluge | V IN | DVDD = 3.3 V | 1.5 | | | v |
| Input Low Voltage | VIL | DVDD = 5.V | 1.5 | | 1.4 | v |
| | VIL | DVDD = 3.3 V | | | 1.4 | v |
| DIGITAL SUPPLIES | | DVDD, DGND | | | 1.0 | v |
| Digital Supply Range | | | 3.3 | | 5.5 | v |
| Ouiescent Current | | Enabled | 5.5 | 50 | د.د | - |
| | | Disabled | | 0.6 | | μΑ |
| We to DOND Hoad Boom | | | | | | μA V |
| +Vs to DGND Head Room | | | | ≥3.3 | | v |

¹ When referring to a single function of a multifunction pin, only the portion of the pin name that is relevant to the specification is listed. For full pin names of multifunction pins, refer to the Pin Configuration and Function Descriptions section.

±5 V ADC DRIVER

 $T_A = 25^{\circ}C$, $+V_S = +5$ V, $-V_S = -5$ V, unless otherwise specified. See Figure 1 for the P1 and M1 amplifiers. $R_L = 1$ k Ω when differential, and $R_L = 500 \Omega$ when single-ended.

| DYNAMIC PERFORMANCE —3 dB Bandwidth | When used differentially, $V_{OUT} = 0.1 V p-p$ When used differentially, $V_{OUT} = 2.0 V p-p$ When P1 is used, $V_{OUT} = 50 \text{ mV } p-p$ | | | | 1 |
|--|---|----------|------------|-------------|---------|
| –3 dB Bandwidth | When used differentially, $V_{OUT} = 2.0 V p-p$ | | | | |
| | When used differentially, $V_{OUT} = 2.0 V p-p$ | | 38 | | MHz |
| | When P1 is used $V_{m} = 50 \text{ mV}/\text{m}$ | | 16 | | MHz |
| | 1 vitient F i is used, vout – 30 m p-p | | 55 | | MHz |
| | When P1 is used, $V_{OUT} = 1.0 \text{ V p-p}$ | | 17 | | MHz |
| | When M1 is used, $V_{OUT} = 50 \text{ mV } p-p$ | | 45 | | MHz |
| | When M1 is used, $V_{OUT} = 1.0 \text{ V p-p}$ | | 21 | | MHz |
| Overdrive Recovery Time | Positive recovery/negative recovery for P1 | | 200/180 | | ns |
| , | Positive recovery/negative recovery for M1 | | 100/100 | | ns |
| Slew Rate | When differentially used, $V_{OUT} = 2 V$ step | | 57 | | V/µs |
| | When P1 or M1 is single-ended, Vout = 1 V step | | 30 | | V/μs |
| Settling Time 0.1% | When used differentially, $V_{OUT} = 2 V$ step | | 95 | | ns |
| | When P1 is used, $V_{OUT} = 1 V$ step | | 80 | | ns |
| | When M1 is used, $V_{OUT} = 1 V$ step | | 80 | | ns |
| NOISE/DISTORTION PERFORMANCE | | | | | |
| Harmonic Distortion (HD2/HD3) | When used differentially, $f_c = 100 \text{ kHz}$, $V_{OUT} = 4 \text{ V p-p}$ | | -105/-109 | | dBc |
| | When used differentially, $f_c = 1 \text{ MHz}$, $V_{OUT} = 4 \text{ V p-p}$ | | -75/-73 | | dBc |
| | When P1 is used, $f_c = 100 \text{ kHz}$, $V_{OUT} = 2 \text{ V p-p}$ | | -112/-108 | | dBc |
| | When P1 is used, $f_c = 1$ MHz, $V_{OUT} = 2$ V p-p | | -75/-73 | | dBc |
| | When M1 is used, $f_c = 100 \text{ kHz}$, $V_{OUT} = 2 \text{ V p-p}$ | | -98/-103 | | dBc |
| | When M1 is used, $f_c = 1 \text{ MHz}$, $V_{OUT} = 2 \text{ V p-p}$ | | -70/-69 | | dBc |
| Referred to Input (RTI) Voltage Noise | For P1, f = 10 Hz | | 55 | | nV/√Hz |
| | For P1, $f = 100 \text{ kHz}$ | | 5 | | nV/√Hz |
| Referred to Output (RTO) Voltage Noise | For P1 and M1, $f = 10$ Hz, measured at VOUT2 | | 95 | | nV/√Hz |
| | For P1 and M1, $f = 100 \text{ kHz}$, measured at VOUT2 | | 16 | | nV/√Hz |
| Input Current Noise | f = 100 kHz, referred to P1 | | 1.1 | | pA/√Hz |
| DC PERFORMANCE | | | | | 1 |
| Output Offset Voltage | Differential | | 0.125 | 0.5 | mV |
| Output Offset Voltage Drift | Differential | | 0.7 | 13 | μV/°C |
| Input Offset Voltage | Single-ended, P1 only | | 50 | 180 | μV |
| input onset voltage | Single-ended, M1 only | | 40 | 180 | μV |
| Input Offset Voltage Drift | Single-ended, P1 only | | 0.2 | 4.75 | μV/°C |
| input onset voltage bint | Single-ended, M1 only | | 0.4 | 3.6 | μV/°C |
| Input Bias Current | P1 only at VIN1 pin | | 60 | 220 | nA |
| input blub current | P1 only at RF1 pin | | 60 | 325 | nA |
| | M1 at REF pin | | 60 | 200 | nA |
| Input Offset Current | P1 only | | 60 | 260 | nA |
| Open-Loop Gain | P1 only, $V_{OUT} = \pm 2 V$ | 102 | 112 | 200 | dB |
| Gain | M1 only | 1.99 | 1.9996 | 2.01 | V/V |
| Gain Error | | -0.5 | | +0.5 | % |
| Gain Error Drift | | 0.5 | 0.6 | +0.5 1.9 | ppm/°C |
| INPUT CHARACTERISTICS | | | 0.0 | | |
| Input Resistance | VIN1 and REF | | 200 | | MΩ |
| Input Capacitance | VIN1 and REF | | 200 1.4 | | pF |
| Input Common-Mode Voltage Range | | -5 | 1.4 | +3.8 | рг V |
| Common-Mode Rejection Ratio | For P1, $V_{CM} = \pm 3.0 \text{ V}$ | -5 82 | 100 | ±2.0 | v dB |

Data Sheet

ADA4350

| Parameter | Test Conditions/Comments ¹ | Min | Тур | Мах | Unit |
|---------------------------------------|--|-------|-------|------|--------|
| OUTPUT CHARACTERISTICS | | | | | |
| Output Voltage Swing | $R_L = no load, single-ended$ | ±4.8 | ±4.83 | | V |
| | $R_L = 500 \Omega$, single-ended | ±4.55 | ±4.6 | | V |
| Output Common-Mode Voltage Range | | -5 | | +3.8 | V |
| Linear Output Current | P1 or M1, V _{OUT} = 2 V p-p, 60 dB SFDR | | 18 | | mA rms |
| | Differential output, Vout = 4 V p-p, 60 dB SFDR | | 18 | | mA rms |
| Short Circuit Current | P1 or M1, sinking/sourcing | | 43/76 | | mA |
| Capacitive Load Drive | When used differentially at each VOUTx, 30% overshoot, $V_{\text{OUT}} = 200 \text{ mV } p\text{-}p$ | | 33 | | pF |
| | When P1/M1 is used, 30% overshoot, $V_{OUT} = 100 \text{ mV p-p}$ | | 47 | | рF |
| POWER SUPPLY | | | | | |
| Operating Range | | 3.3 | | 12 | V |
| Positive Power Supply Rejection Ratio | For P1 | 90 | 106 | | dB |
| | For M1 | 86 | 100 | | dB |
| Negative Power Supply Rejection Ratio | For P1 | 80 | 100 | | dB |
| | For M1 | 78 | 90 | | dB |

 $^{\rm 1}$ P1 and M1 within this table refer to the amplifiers shown in Figure 1.

5 V FULL SYSTEM

 T_{A} = 25°C, +V_{\text{S}} = 5 V, -V_{\text{S}} = 0 V, R_{F} = 1 k Ω differential, unless otherwise specified.

Table 5.

| Parameter | Test Conditions/Comments | Min | Тур | Max | Unit |
|---------------------------------------|---|-----|---------|------|--------|
| DYNAMIC PERFORMANCE | | | | | |
| –3 dB Bandwidth | $G = -5$, $V_{OUT} = 200 \text{ mV p-p}$ | | 15 | | MHz |
| | G = -5, V _{OUT} = 1 V p-p | | 14 | | MHz |
| Slew Rate | V _{OUT} = 2 V step, 10% to 90% | | 30 | | V/µs |
| HARMONIC PERFORMANCE | | | | | |
| Harmonic Distortion (HD2/HD3) | $G = -5$, $f_C = 100 \text{ kHz}$ | | -85/-94 | | dBc |
| | $G = -5$, $f_C = 1 MHz$ | | -66/-75 | | dBc |
| Input Voltage Noise | f = 10 Hz | | 92 | | nV/√Hz |
| | f = 100 kHz | | 4.4 | | nV/√Hz |
| DC PERFORMANCE | | | | | |
| Input Bias Current | At 25℃ | | ±0.35 | ±1.6 | pА |
| | At 85℃ | | ±8.5 | ±30 | pA |
| INPUT CHARACTERISTICS | | | | | |
| Input Resistance | Common mode | | 100 | | GΩ |
| Input Capacitance | Common mode | | 2 | | рF |
| | Differential mode | | 3 | | pF |
| Input Common-Mode Voltage Range | CMRR > 80 dB | 0.5 | | 3.8 | V |
| | CMRR > 68 dB | 0 | | 3.9 | V |
| Common-Mode Rejection | $V_{CM} = \pm 0.5 V$ | 88 | 94 | | dB |
| OUTPUT CHARACTERISTICS | | | | | |
| Linear Output Current | V _{OUT} = 1 V p-p, 60 dB SFDR | | 9 | | mA rms |
| Short-Circuit Current | Sinking/sourcing, $R_L < 1 \Omega$ | | 41/63 | | mA |
| Settling Time to 0.1% | $G = -5$, $V_{OUT} = 2V$ step | | 130 | | ns |
| POWER SUPPLY | | | | | |
| Operating Range | | 3.3 | | 12 | V |
| Quiescent Current | Enabled | | 8 | 9 | mA |
| | M1 disabled (see Figure 1) | | 6.5 | | mA |
| | All disabled | | 2 | | μA |
| Positive Power Supply Rejection Ratio | | | 86 | | dB |
| Negative Power Supply Rejection Ratio | | | 80 | | dB |
| DIGITAL SUPPLIES (DVDD, DGND) | DVDD, DGND | | | | |
| Digital Supply Range | | 3.3 | | 5.5 | V |
| Quiescent Current | Enabled | | 50 | | μA |
| | Disabled | | 0.6 | | μA |
| +Vs to DGND Head Room | | | ≥3.3 | | v |

5 V FET INPUT AMPLIFIER

 $T_{\rm A}$ = 25°C, +V_{\rm S} = 5 V, -V_{\rm S} = 0 V, $R_{\rm L}$ = 1 k Ω , unless otherwise specified.

Table 6.

| Parameter | Test Conditions/Comments | Min | Тур | Max | Unit |
|---------------------------------------|--|--------------|--------------|-------|--------|
| DYNAMIC PERFORMANCE | | | | | |
| –3 dB Bandwidth | G = -5, V _{OUT} = 100 mV p-p | | 25 | | MHz |
| | G = -5, V _{OUT} = 1 V p-p | | 24 | | MHz |
| Gain Bandwidth Product | | | 175 | | MHz |
| Slew Rate | V _{OUT} = 2 V step, 10% to 90% | | 56 | | V/µs |
| Settling Time to 0.1% | $G = -5$, $V_{OUT} = 2 V$ step | | 60 | | ns |
| NOISE/HARMONIC PERFORMANCE | | | | | |
| Harmonic Distortion (HD2/HD3) | f = 100 kHz, V _{OUT} = 1 V p-p, G = -5 | | -113/-117 | | dBc |
| | f = 1 MHz, V _{OUT} = 1 V p-p, G = -5 | | -82/-83 | | dBc |
| Input Voltage Noise | f = 10 Hz | | 92 | | nV/√Hz |
| | f = 100 kHz | | 4.4 | | nV/√Hz |
| DC PERFORMANCE | | | | | |
| Input Offset Voltage | | | 25 | 80 | μV |
| Input Offset Voltage Drift | From –40°C to +85°C | | 0.1 | 1.5 | μV/°C |
| | From 25°C to 85°C | | 0.05 | 1 | μV/°C |
| Input Bias Current | At 25°C | | ±0.35 | ±1.6 | pА |
| | At 85°C | | ±8.5 | ±30 | pA |
| Input Bias Offset Current | At 25°C | | ±0.25 | ±1.25 | pА |
| | At 85°C | | ±0.4 | | pA |
| Open-Loop Gain | V _{OUT} = 1.5 V to 3.5 V | 98 | 102 | | dB |
| INPUT CHARACTERISTICS | | | | | |
| Input Resistance | Common mode | | 100 | | GΩ |
| Input Capacitance | Common mode | | 2 | | pF |
| | Differential mode | | 3 | | pF |
| Input Common-Mode Voltage Range | CMRR > 80 dB | 0.5 | | 3.8 | V |
| | CMRR > 68 dB | 0 | | 3.9 | V |
| Common-Mode Rejection Ratio | $V_{CM} = \pm 0.5 V$ | 88 | 94 | | dB |
| OUTPUT CHARACTERISTICS | | | | | |
| Output Overdrive Recovery Time | $V_{OUT} = V_s \pm 10\%$, positive/negative | | 60/50 | | ns |
| Output Voltage Swing | $G = +21$, $R_F = 1 \text{ k}\Omega$, R_L open measured at FBx | 1.15 to 3.46 | 0.86 to 3.66 | | V |
| 1 5 5 | $G = +21$, $R_F = 100 \text{ k}\Omega$, R_L open measured at FBx | 0.27 to 4.80 | 0.08 to 4.87 | | V |
| Linear Output Current | V _{OUT} = 1 V p-p, 60 dB SFDR | | 10 | | mA rms |
| Short-Circuit Current | Sinking/sourcing | | 32/38 | | mA |
| POWER SUPPLY | | | | | t |
| Operating Range | | 3.3 | | 12 | v |
| Positive Power Supply Rejection Ratio | | 90 | 100 | | dB |
| Negative Power Supply Rejection Ratio | | 86 | 100 | | dB |

5 V INTERNAL SWITCHING NETWORK AND DIGITAL PINS

 $T_A = 25^{\circ}C$, $+V_S = 5$ V, $-V_S = 0$ V, unless otherwise specified. See Figure 1 for sampling and feedback switches position.

| Parameter | Symbol | Test Conditions/Comments | Min | Тур | Max | Unit |
|---|----------------------------|--|-----|------|------|------|
| FEEDBACK/SAMPLE ANALOG SWITCH | | | | | | |
| Analog Signal Range | | | 0 | | 5 | V |
| Switch On Resistance | | | | | | |
| Feedback | Ron, FB | S0 to S2, $V_{CM} = 2.5 V$ | | 308 | 390 | Ω |
| | | $T_A = 85^{\circ}C$ | | 382 | | Ω |
| | | S3 to S5, $V_{CM} = 2.5 V$ | | 308 | 390 | Ω |
| | | $T_A = 85^{\circ}C$ | | 384 | | Ω |
| Sampling | Ron, s | S6 to S8, $V_{CM} = 2.5 V$ | | 610 | 770 | Ω |
| | | $T_A = 85^{\circ}C$ | | 762 | | Ω |
| | | S9 to S11, $V_{CM} = 2.5 V$ | | 612 | 770 | Ω |
| | | $T_A = 85^{\circ}C$ | | 764 | | Ω |
| On-Resistance Match Between Channels | | | | | | |
| Feedback Resistance | $\Delta R_{\text{ON, FB}}$ | $V_{CM} = 2.5 V$ | | 3 | 21 | Ω |
| Sampling Resistance | $\Delta R_{ON, S}$ | $V_{CM} = 2.5 V$ | | 3 | 23 | Ω |
| SWITCH LEAKAGE CURRENTS | | | | | | |
| Sampling and Feedback Switch Off Leakage | Is (OFF) | | | ±0.4 | ±1.2 | pА |
| | | $T_A = 85^{\circ}C$ | | ±30 | ±80 | pА |
| DYNAMIC CHARACTERISTICS | | | | | | |
| Power-On Time | ton | DVDD = 3.3 V | | 105 | | ns |
| Power-Off Time | toff | DVDD = 3.3 V | | 65 | | ns |
| Off Isolation | | $R_L = 50 \Omega$, $f = 1 MHz$ | | | | |
| Feedback Switches | | | | -93 | | dB |
| Sampling Switches | | | | -116 | | dB |
| Channel to Channel Crosstalk | | $R_L = 50 \Omega$, $f = 1 MHz$ | | -83 | | dB |
| Worst Case Switch Feedback Capacitance (Switch Off) | CFB (OFF) | | | 0.1 | | рF |
| THRESHOLD VOLTAGES FOR DIGITAL INPUT PINS | | EN, MODE, DGND, LATCH/P0, SCLK/P1, SDO/P2, SDI/P3, CS/P4 ¹ | | | | |
| Input High Voltage | VIH | DVDD = 5V | 2.0 | | | V |
| | | DVDD = 3.3 V | 1.5 | | | V |
| Input Low Voltage | VIL | DVDD = 5V | | | 1.4 | V |
| | | DVDD = 3.3 V | | | 1.0 | V |
| DIGITAL SUPPLIES | | DVDD, DGND | | | | |
| Digital Supply Range | | | 3.3 | | 5.5 | v |
| Quiescent Current | | Enabled | | 50 | | μA |
| | | Disabled | | 0.6 | | μA |
| +Vs to DGND Head Room | | | | ≥3.3 | | v |

¹ When referring to a single function of a multifunction pin, only the portion of the pin name that is relevant to the specification is listed. For full pin names of multifunction pins, refer to the Pin Configuration and Function Descriptions section.

5 V ADC DRIVER

 $T_A = 25^{\circ}C$, $+V_S = 5 V$, $-V_S = 0 V$, unless otherwise specified. See Figure 1 for the P1 and M1 amplifiers, $R_L = 1 k\Omega$ when differential, and $R_L = 500 \Omega$ when single-ended.

| Parameter | Test Conditions/Comments ¹ | Min | Тур | Max | Unit |
|--|---|------|-----------|------|--------|
| DYNAMIC PERFORMANCE | | | | | |
| –3 dB Bandwidth | When used differentially, $V_{OUT} = 0.1 V p-p$ | | 33 | | MHz |
| | When used differentially, $V_{OUT} = 2.0 \text{ V p-p}$ | | 16 | | MHz |
| | When P1 is used, $V_{OUT} = 50 \text{ mV } p-p$ | | 47 | | MHz |
| | When P1 is used, $V_{OUT} = 1.0 \text{ V p-p}$ | | 16 | | MHz |
| | When M1 is used, $V_{OUT} = 50 \text{ mV p-p}$ | | 37 | | MHz |
| | When M1 is used, $V_{OUT} = 1.0 \text{ V p-p}$ | | 18 | | MHz |
| Overdrive Recovery Time | For P1, positive recovery/negative recovery | | 200/200 | | ns |
| · | For M1, positive recovery/negative recovery | | 140/120 | | ns |
| Slew Rate | When differentially used, $V_{OUT} = 2 V$ step | | 37 | | V/µs |
| | When P1 or M1 is single-ended, $V_{OUT} = 1 V$ step | | 20 | | V/μs |
| Settling Time 0.1% | When used differentially, $V_{OUT} = 2 V$ step | | 75 | | ns |
| J | When P1 is used, Vout = 1 V step | | 60 | | ns |
| | When M1 is used, $V_{OUT} = 1 V$ step | | 60 | | ns |
| NOISE/DISTORTION PERFORMANCE | | | | | |
| Harmonic Distortion (HD2/HD3) | When used differentially, $f_c = 100 \text{ kHz}$, $V_{out} = 1 \text{ V p-p}$ | | -117/-116 | | dBc |
| | When used differentially, $f_c = 1 \text{ MHz}$, $V_{out} = 1 \text{ V p-p}$ | | -80/-85 | | dBc |
| | When P1 is used, $f_c = 100 \text{ kHz}$, $V_{OUT} = 500 \text{ mV p-p}$ | | -108/-115 | | dBc |
| | When P1 is used, $f_c = 1 \text{ MHz}$, $V_{OUT} = 500 \text{ mV p-p}$ | | -80/-83 | | dBc |
| | When M1 is used, $f_c = 100 \text{ kHz}$, $V_{OUT} = 500 \text{ mV p-p}$ | | -103/-107 | | dBc |
| | When M1 is used, $f_c = 1 \text{ MHz}$, $V_{OUT} = 500 \text{ mV p-p}$ | | -75/-78 | | dBc |
| Referred to Input (RTI) Voltage Noise | For P1, $f = 10 Hz$ | | 60 | | nV/√Hz |
| | For P1, f = 100 kHz | | 5.2 | | nV/√Hz |
| Referred to Output (RTO) Voltage Noise | For P1 and M1, $f = 10$ Hz, measured at VOUT2 | | 140 | | nV/√Hz |
| | For P1 and M1, $f = 100 \text{ kHz}$, measured at VOUT2 | | 18 | | nV/√Hz |
| Input Current Noise | f = 100 kHz, referred to P1 | | 1.1 | | pA/√Hz |
| DC PERFORMANCE | | | | | |
| Output Offset Voltage | Differential | | 0.15 | 0.75 | mV |
| Input Offset Voltage Drift | Differential | | 0.6 | 16 | μV/°C |
| Output Offset Voltage | Single-ended, P1 only | | 60 | 275 | μV |
| | Single-ended, M1 only | | 70 | 250 | μV |
| Input Offset Voltage Drift | Single-ended, P1 only | | 0.1 | 5.9 | μV/°C |
| | Single-ended, M1 only | | 0.3 | 4.5 | μV/°C |
| Input Bias Current | P1 only at VIN1 pin | | 60 | 230 | nA |
| | P1 only at RF1 pin | | 60 | 350 | nA |
| | M1 only at REF pin | | 60 | 200 | nA |
| Input Offset Current | P1 only | | 60 | 270 | nA |
| Open-Loop Gain | P1 only, V _{OUT} = 1.5 V to 3.5 V | 94 | 100 | | dB |
| Gain | M1 only | 1.99 | 1.9995 | 2.01 | V/V |
| Gain Error | | -0.5 | | +0.5 | % |
| Gain Error Drift | | | 0.6 | 3.4 | ppm/°C |

| Parameter | Test Conditions/Comments ¹ | Min | Тур | Max | Unit |
|---------------------------------------|---|--------------|----------------|-----|--------|
| INPUT CHARACTERISTICS | | | | | |
| Input Resistance | VIN1 and REF | | 200 | | MΩ |
| Input Capacitance | VIN1 and REF | | 1.4 | | pF |
| Input Common-Mode Voltage Range | | 0 | | 3.9 | V |
| Common-Mode Rejection Ratio | For P1, $V_{CM} = \pm 0.5 V$ | 84 | 94 | | dB |
| OUTPUT CHARACTERISTICS | | | | | |
| Output Voltage Swing | R∟ = no load, single-ended | 0.15 to 4.85 | 0.125 to 4.875 | | V |
| | $R_L = 500 \Omega$, single-ended | 0.28 to 4.72 | 0.24 to 4.76 | | V |
| Output Common-Mode Voltage Range | | 0 | | 3.9 | V |
| Linear Output Current | For P1or M1, V _{OUT} = 1 V p-p, 60 dB SFDR | | 4 | | mA rms |
| | Differential output, Vout = 1 V p-p, 60 dB SFDR | | 10 | | mA rms |
| Short-Circuit Current | For P1 or M1, sinking/sourcing | | 41/63 | | mA |
| Capacitive Load Drive | When used differentially at each VOUTx, 30% overshoot, $V_{OUT} = 100 \text{ mV } p$ -p | | 33 | | pF |
| | When P1/M1 is used, 30% overshoot, $V_{OUT} = 50 \text{ mV } p \cdot p$ | | 47 | | pF |
| POWER SUPPLY | | | | | |
| Operating Range | | 3.3 | | 12 | V |
| Positive Power Supply Rejection Ratio | For P1 | 86 | 104 | | dB |
| | For M1 | 80 | 94 | | dB |
| Negative Power Supply Rejection Ratio | For P1 | 80 | 92 | | dB |
| | For M1 | 76 | 88 | | dB |

¹ P1 and M1 within this table refer to the amplifiers shown in Figure 1.

TIMING SPECIFICATIONS

All input signals are specified with $t_R = t_F = 2$ ns (10% to 90% of DVDD) and timed from a voltage threshold level of $V_{TH} = 1.3$ V at DVDD = 3.3 V or $V_{TH} = 1.7$ V at DVDD = 5 V. Guaranteed by characterization; not production tested. See Figure 2 and Figure 3.

Table 9.

| | | | DVDD = 3.3 V | | DVDD = 5 V | |
|-----------------|---|-----|--------------|-----|------------|------|
| Parameter | Description ¹ | Min | Мах | Min | Max | Unit |
| t ₁ | SCLK period. | 20 | | 20 | | ns |
| t ₂ | SCLK positive pulse width. | 10 | | 10 | | ns |
| t ₃ | SCLK negative pulse width. | 10 | | 10 | | ns |
| t4 | CS setup time. The time required to begin sampling data after CS goes low. | 1 | | 1 | | ns |
| t ₅ | \overline{CS} hold time. The amount of time required for \overline{CS} to be held low after the last data bit is sampled before bringing \overline{CS} high. Data is latched on the \overline{CS} rising edge. If LATCH is held low, data is also applied on the \overline{CS} rising edge. | 7 | | 5 | | ns |
| t ₆ | CS positive pulse width. The amount of time required between consecutive words. | 2 | | 1 | | ns |
| t7 | Data setup time. The amount of time the data bit (SDI) must be set before sampling on the falling edge of SCLK. | 1 | | 1 | | ns |
| t ₈ | Data hold time. The amount of time SDI must be held after the falling edge of SCLK for valid data to be sampled. | 2 | | 2 | | ns |
| t9 | Data latched to the internal switches updated. The amount of time it takes from the latched data being applied until the internal switches are updated. LATCH disabled referenced from the rising edge of \overline{CS} . | | 145 | | 140 | ns |
| | LATCH enabled referenced from the falling edge of LATCH. | | | | | |
| t ₁₀ | LATCH negative pulse width. | 3 | | 3 | | ns |
| t_{11}^{2} | SCLK rising edge to SDO valid. The amount of time between the SCLK rising edge and the valid SDO transitions ($CL_{SDO}^3 = 20 \text{ pF}$). | | 15 | | 10 | ns |
| t ₁₂ | $\overline{\text{CS}}$ rising edge to the SCLK falling edge. The amount of time required to prevent a 25 th SCLK edge from being recognized (only 24 bits allowed for valid word). | 1 | | 1 | | ns |

¹ When referring to a single function of a multifunction pin, only the portion of the pin name that is relevant to the specification is listed. For full pin names of multifunction pins, refer to the Pin Configuration and Function Descriptions section.

² This is while in daisy-chain mode and in readback mode.

³ CL_{SDO} is the capacitive load on the SDO output.

Timing Diagrams for Serial Mode

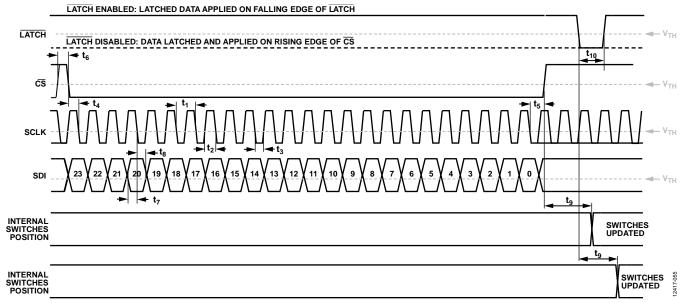
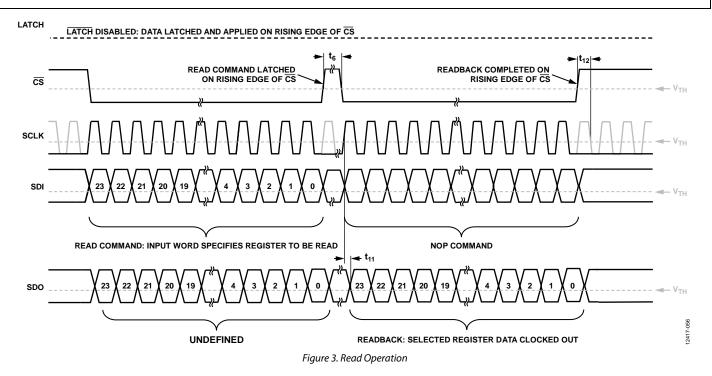


Figure 2. Write Operation



ABSOLUTE MAXIMUM RATINGS

Table 10.

| 1.0010 1.00 | |
|--|---------------------|
| Parameter | Rating |
| Analog Supply Voltage | 14 V |
| Digital Supply Voltage | 5.5 V |
| Power Dissipation | See Figure 4 |
| Common-Mode Input Voltage | \pm Vs \pm 0.3V |
| Differential Input Voltage | ±0.7 V |
| Input Current (IN-N, IN-P, VIN1, RF1, and REF) | 20 mA |
| Storage Temperature Range | –65°C to +125°C |
| Operating Temperature Range | -40°C to +85°C |
| Lead Temperature (Soldering, 10 sec) | 300°C |
| Junction Temperature | 150°C |

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

THERMAL RESISTANCE

 θ_{JA} is specified for the worst case conditions, that is, θ_{JA} is specified for a device soldered in a circuit board for surfacemount packages. Table 11 lists the θ_{JA} for the ADA4350.

Table 11. Thermal Resistance

| Package Type | θ」Α | Unit |
|---------------|------|------|
| 28-Lead TSSOP | 72.4 | °C/W |

MAXIMUM POWER DISSIPATION

The maximum safe power dissipation for the ADA4350 is limited by the associated rise in junction temperature (T_J) on the die. At approximately 150°C, which is the glass transition temperature, the properties of the plastic change. Even temporarily exceeding this temperature limit may change the stresses that the package exerts on the die, permanently shifting the parametric performance of the ADA4350. Exceeding a junction temperature of 175°C for an extended period can result in changes in silicon devices, potentially causing degradation or loss of functionality.

The power dissipated in the package (P_D) is the sum of the quiescent power dissipation and the power dissipated in the die due to the ADA4350 output load drive.

The quiescent power dissipation is the voltage between the supply pins $(\pm V_s)$ multiplied by the quiescent current (I_s).

 P_D = Quiescent Power + (Total Drive Power – Load Power)

$$P_{D} = \left(\pm V_{S} \times I_{S}\right) + \left(\frac{\pm V_{S}}{2} \times \frac{V_{OUT}}{R_{L}}\right) - \frac{V_{OUT}^{2}}{R_{L}}$$

Consider rms output voltages. If R_L is referenced to $-V_S$, as in single-supply operation, the total drive power is $+V_S \times I_{OUT}$. If the rms signal levels are indeterminate, consider the worst case, when $V_{OUT} = +V_S/4$ for R_L to midsupply for dual supplies and $V_{OUT} = +V_S/2$ for single supply.

$$P_D = \left(+V_S \times I_S\right) + \frac{\left(V_{OUT}\right)^2}{R_L}$$

Airflow increases heat dissipation, effectively reducing θ_{JA} . In addition, more metal directly in contact with the package leads and exposed pad from metal traces, through holes, ground, and power planes reduces θ_{JA} .

Figure 4 shows the maximum safe power dissipation in the package vs. the ambient temperature on a JEDEC standard 4-layer board. θ_{JA} values are approximations.

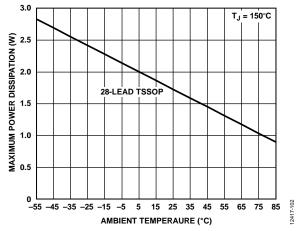


Figure 4. Maximum Power Dissipation vs. Ambient Temperature for a 4-Layer Board

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

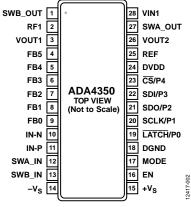


Figure 5. Pin Configuration

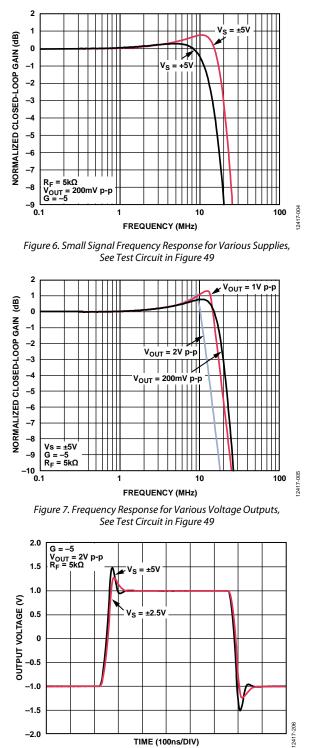
Table 12. Pin Function Descriptions

| Pin No. | Mnemonic | Description |
|---------|----------|--|
| 1 | SWB_OUT | Switch Group B (S3 to S5 and S9 to S11) Output. |
| 2 | RF1 | Feedback Resistor for Output Differential Amplifier. |
| 3 | VOUT1 | Differential Amplifier Output 1. |
| 4 | FB5 | Feedback Pin 5 for FET Input Amplifier. |
| 5 | FB4 | Feedback Pin 4 for FET Input Amplifier. |
| 6 | FB3 | Feedback Pin 3 for FET Input Amplifier. |
| 7 | FB2 | Feedback Pin 2 for FET Input Amplifier. |
| 8 | FB1 | Feedback Pin 1 for FET Input Amplifier. |
| 9 | FB0 | Feedback Pin 0 for FET Input Amplifier. |
| 10 | IN-N | FET Input Amplifier Inverting Input. |
| 11 | IN-P | FET Input Amplifier Noninverting Input. |
| 12 | SWA_IN | Switch Group A (S0 to S2 and S6 to S8) Input. |
| 13 | SWB_IN | Switch Group B (S3 to S5 and S9 to S11) Input. |
| 14 | -Vs | Analog Negative Supply. |
| 15 | +Vs | Analog Positive Supply. |
| 16 | EN | Enable Pin. |
| 17 | MODE | Mode Pin. Use this pin to switch between the SPI interface and the parallel interface. |
| 18 | DGND | Digital Ground. |
| 19 | LATCH/P0 | Latch Bit in the Serial Mode (LATCH). Parallel Data Bit 0 in parallel mode (P0). |
| 20 | SCLK/P1 | Digital Clock in Serial Mode (SCLK). Parallel Data Bit 1 in parallel mode (P1). |
| 21 | SDO/P2 | Serial Data Out in Serial Mode (SDO). Parallel Data Bit 2 in parallel mode (P2). |
| 22 | SDI/P3 | Serial Data In in Serial Mode (SDI). Parallel Data Bit 3 in parallel mode (P3). |
| 23 | CS/P4 | Select Bit in Serial Mode (CS). Parallel Data Bit 4 in parallel mode (P4). |
| 24 | DVDD | Digital Positive Supply. |
| 25 | REF | Reference for the ADC Driver at M1. |
| 26 | VOUT2 | Differential Amplifier Output 2. |
| 27 | SWA_OUT | Switch Group A (S0 to S2 and S6 to S8) Output. |
| 28 | VIN1 | Differential Amplifier Noninverting Input. |

TYPICAL PERFORMANCE CHARACTERISITICS

FULL SYSTEM

These plots are for the full system, which includes the FET input amplifier, the switching network, and the ADC driver. Unless otherwise stated, $R_L = 1 \text{ k}\Omega$ differential. For $Vs = \pm 5 \text{ V}$, DVDD = +5 V, and for Vs = +5 V (or $\pm 2.5 \text{ V}$), DVDD = +3.3 V.



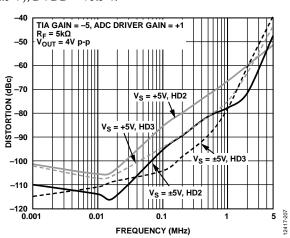


Figure 9. Harmonic Distortion vs. Frequency for Various Supplies, See Test Circuit in Figure 48

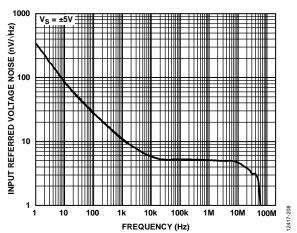


Figure 10. Input Referred Voltage Noise vs. Frequency

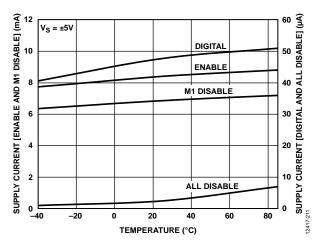
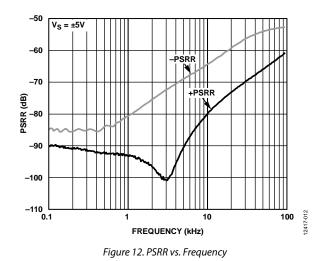


Figure 11. Supply Current vs. Temperature at Different Modes



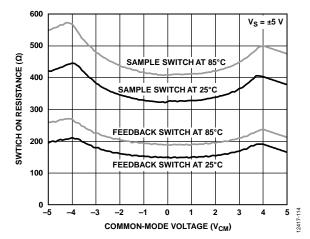


Figure 14. Switch On-Resistance vs. Common-Mode Voltage at Switches for Various Temperature



Figure 13. 0.1% Settling Time, See Test Circuit in Figure 49

FET INPUT AMPLIFIER

Unless otherwise stated, $R_L = 1 \text{ k}\Omega$. For $Vs = \pm 5 \text{ V}$, DVDD = +5 V, and for $Vs = \pm 2.5 \text{ V}$, DVDD = +3.3 V.

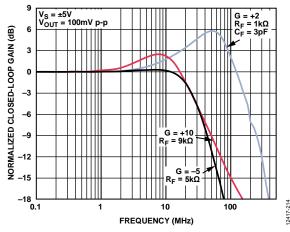


Figure 15. Small Signal Frequency Response for Various Gains, $V_S = \pm 5 V$, See Test Circuit Diagrams in Figure 50 and Figure 51

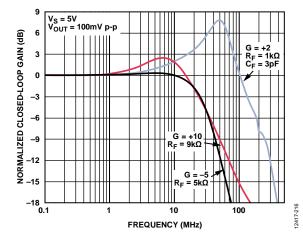


Figure 16. Small Signal Frequency Response for Various Gains, Vs = 5 V, See Test Circuit Diagrams in Figure 50 and Figure 51

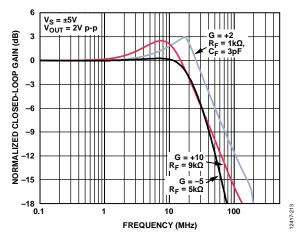


Figure 17. Large Signal Frequency Response for Various Gains, $V_S = \pm 5 V$, See Test Circuit Diagrams in Figure 50 and Figure 51

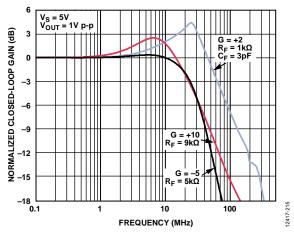


Figure 18. Large Signal Frequency Response for Various Gains, $V_5 = 5 V$, See Test Circuit Diagrams in Figure 50 and Figure 51

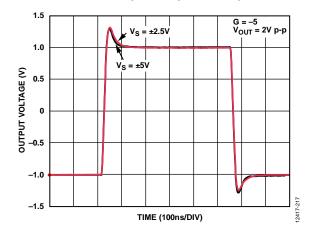


Figure 19. Large Signal Step Response for Various Supplies, G = -5

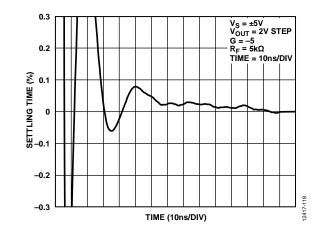
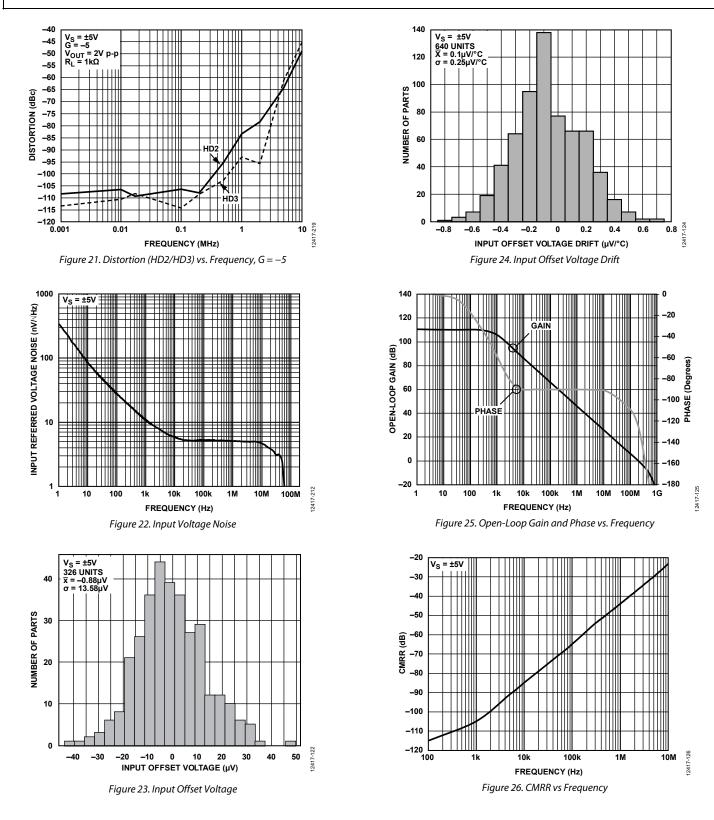
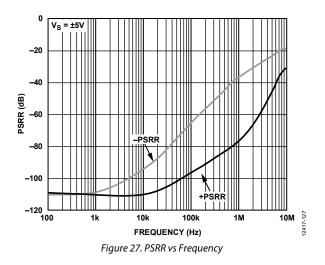


Figure 20. 0.1% Settling Time



Data Sheet

ADA4350



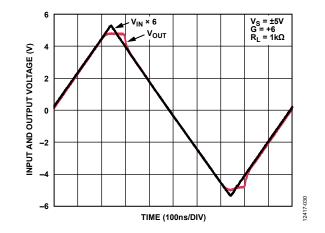


Figure 28. Output Overdrive Recovery when Used as an Amplifier

ADC DRIVER

Unless stated otherwise, $R_L = 1 \text{ k}\Omega$ differential, and $R_L = 500 \Omega$ when single-ended. For $V_S = \pm 5 \text{ V}$, DVDD = +5 V, and for $V_S = +5 \text{ V}$ (or $\pm 2.5 \text{ V}$), DVDD = +3.3 V.

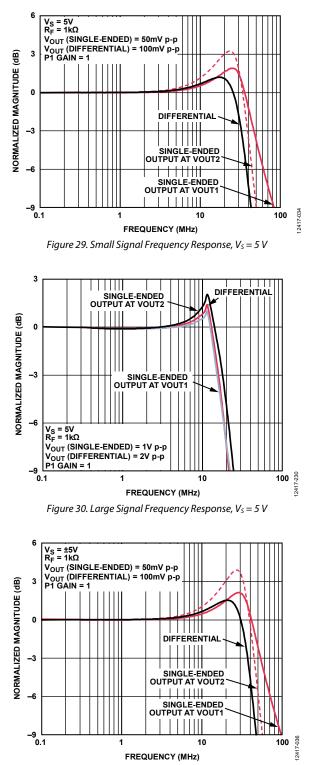
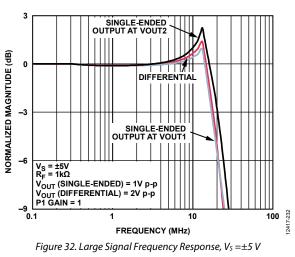


Figure 31. Small Signal Frequency Response, $V_S = \pm 5 V$



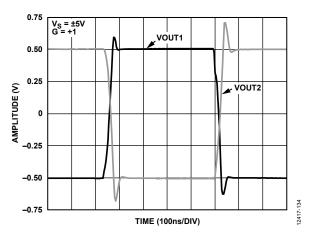


Figure 33. Large Signal Step Response (Single-Ended Output), $V_S = \pm 5 V$

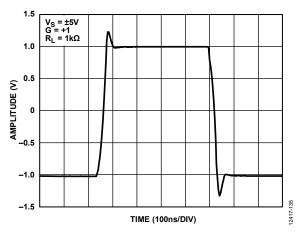


Figure 34. Large Signal Step Response (Differential Output), $V_S = \pm 5 V$

Data Sheet

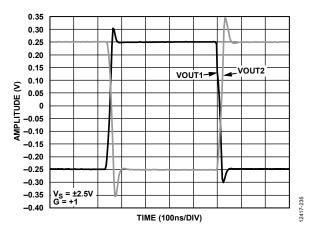


Figure 35. Large Signal Step Response (Single-Ended Output), $V_S = \pm 2.5 V$

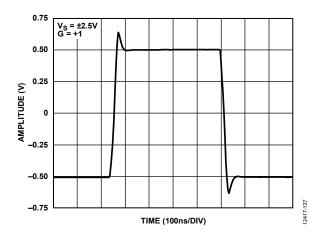


Figure 36. Large Signal Step Response (Differential Output), $V_S = \pm 2.5 V$

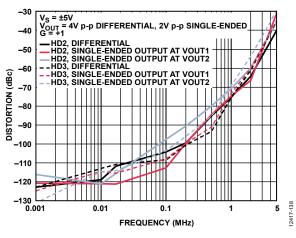
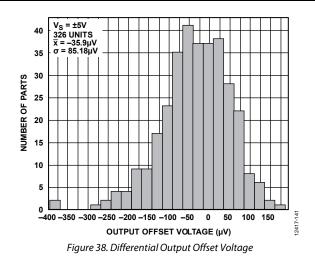
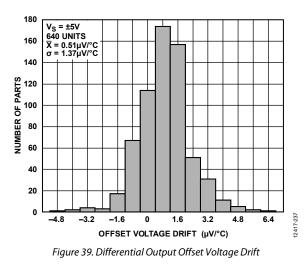
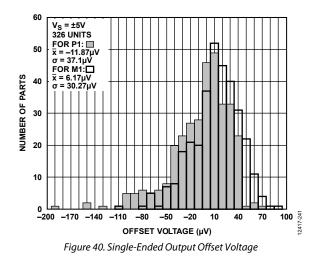


Figure 37. Harmonic Distortion vs. Frequency

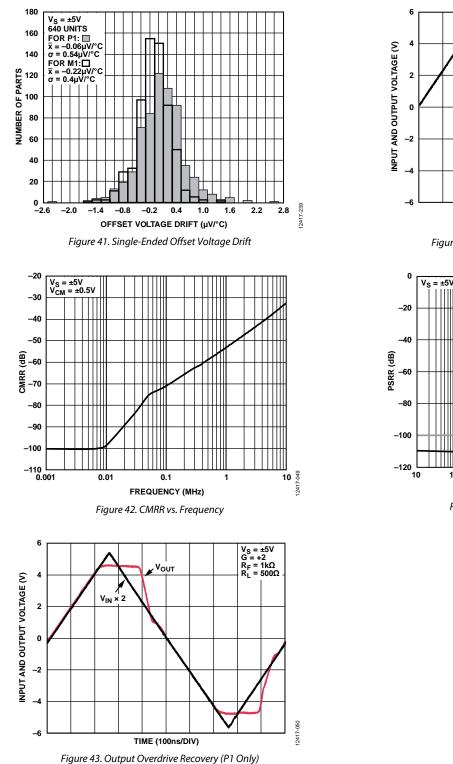


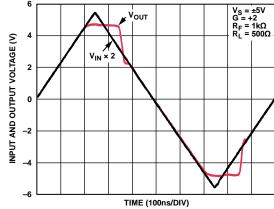




ADA4350

12417-051





VOUT

Figure 44. Output Overdrive Recovery (M1 Only)

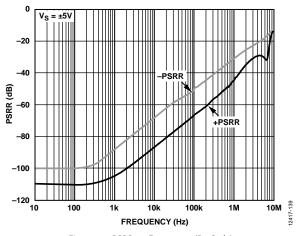
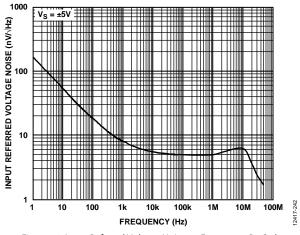
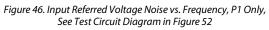


Figure 45. PSRR vs. Frequency (P1 Only)

Data Sheet

ADA4350





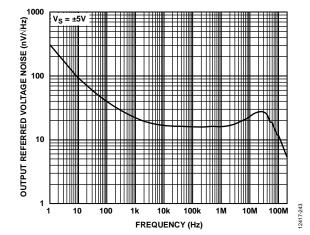
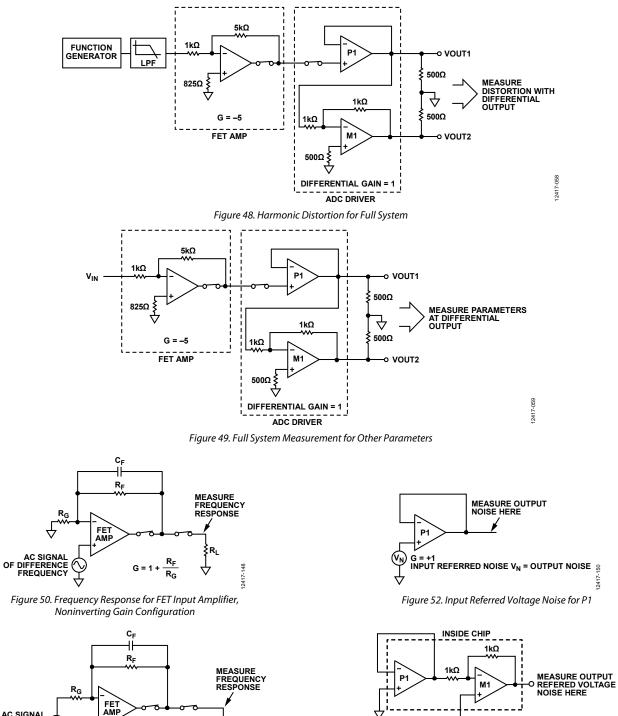


Figure 47. Output Referred Voltage Noise vs. Frequency, P1 and M1, See Test Circuit Diagram in Figure 53

TEST CIRCUITS

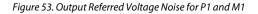
AC SIGNAL OF DIFFERENCE FREQUENCY

V



12417-151

2417-



500Ω

Ľ,

-R_F

G = R_{G}

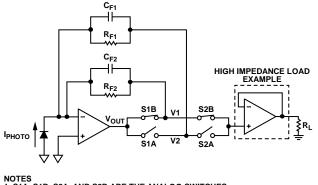
Figure 51. Frequency Response for FET Input Amplifier,

Inverting Gain Configuration

12417-149

THEORY OF OPERATION KELVIN SWITCHING TECHNIQUES

Traditional gain selectable amplifiers use analog switches in a feedback loop to connect discrete external resistors and capacitors to the inverting input by selecting the appropriate feedback path. This approach introduces several errors due to the nonideal nature of the analog switches in the loop. For example, the on-resistance of the analog switch causes voltage and temperature dependent gain errors, while the leakage current causes offset errors, especially at high temperature. The Kelvin switching technique solves this problem by introducing two switches in each gain selection loop, one to connect the transimpedance/ op amp output to the feedback network, and the other to connect the feedback network output to the downstream components. Figure 54 shows a programmable gain transimpedance amplifier with Kelvin switching.



NOTES 1. S1A, S1B, S2A, AND S2B ARE THE ANALOG SWITCHES. R_{Fx} ARE THE FEEDBACK RESISTORS SPECIFIC TO EACH TRANSIMPEDANCE PATH. C_{Fx} ARE THE FEEDBACK CAPACITORS SPECIFIC TO EACH TRANSIMPEDANCE PATH.

Figure 54. Programmable Gain Transimpedance Amplifier with Kelvin Switching Although this technique requires using twice as many switches, the voltage (Vx) in the center node is no longer switch dependent; it is only dependent on the current across the selected resistor (see Equation 1 through Equation 3).

$$V_{OUT} = -I_{PHOTO} \times (R_{F2} + R_{S1B}) \tag{1}$$

$$V1 = V_{OUT} \times (R_{F2}/(R_{F2} + R_{S1B}))$$
(2)

Substituting Equation 1 into Equation 2,

$$V1 = -I_{PHOTO} \times R_{F2} \tag{3}$$

where:

 V_{OUT} is the output of the first amplifier.

 I_{PHOTO} is the current from the photodiode. R_{F2} is the feedback resistor of Transimpedance Path 2.

 R_{S1B} is the recuback resistor of transmipedance R_{S1B} is the switch resistance of the S1B switch.

The switches shown on the right (S2A and S2B) in Figure 54 only have a small output impedance and contribute negligible error if the amplifier drives a high impedance load. In the case of the ADA4350, the high impedance load is the integrated ADC driver.

12417-103

APPLICATIONS INFORMATION CONFIGURING THE ADA4350

See the EVAL-ADA4350RUZ-P user guide for details on the basic configuration of the ADA4350, and how to use the evaluation board. For more details on configuring the ADC driver in a different gain setting, see the ADA4941-1 data sheet.

The gain settings of the ADA4350 can be chosen via the SPI interface or manually through a 5-lead DIP switch.

SELECTING THE TRANSIMPEDANCE GAIN PATHS MANUALLY OR THROUGH THE PARALLEL INTERFACE

In the manual mode (or parallel mode), only five out of the six transimpedance paths can be accessed (FB0 to FB4). Figure 55 shows the simplified schematics of the ADA4350 and the positions of FB0 to FB4. In this example, the first two feedback paths (FB0 and FB1) are configured as two different transimpedance gain paths.

To operate in manual mode or in parallel mode, set the EN pin (Pin 16) and the MODE pin (Pin 17) to Logic 1. In this mode, Pin 19 to Pin 23 represent P0 through P4, respectively. To select one gain, set the corresponding Px pin to Logic 1, and set all other Px pins to Logic 0. Table 13 shows the relationship between the gain select switches (P0 through P4) and the gain path selected. Setting more than one Px pin to Logic 1 results in connecting the selected gain paths in parallel.

| Bit On | Switch Closed | Gain Path Selected |
|--------|---------------|--------------------|
| P0 | S0 and S6 | FBO |
| P1 | S1 and S7 | FB1 |
| P2 | S2 and S8 | FB2 |
| P3 | S3 and S9 | FB3 |
| P4 | S4 and S10 | FB4 |

SELECTING THE TRANSIMPEDANCE GAIN PATHS THROUGH THE SPI INTERFACE (SERIAL MODE)

For serial mode operation, set the EN pin (Pin 16) to Logic 1 and the MODE pin (Pin 17) to Logic 0. In serial mode, Pin 19 is $\overrightarrow{\text{LATCH}}$, Pin 20 is SCLK, Pin 21 is SDO, Pin 22 is SDI, and Pin 23 is $\overrightarrow{\text{CS}}$. Serial mode operation uses a 24-bit command to configure each individual switch, S0 through S11, as well as additional options. Table 14 shows the 24-bit map used in serial mode operation. Table 15 shows the example codes that select the various transimpedance gain paths.

Multifunction pin names may be referenced by their relevant function only.

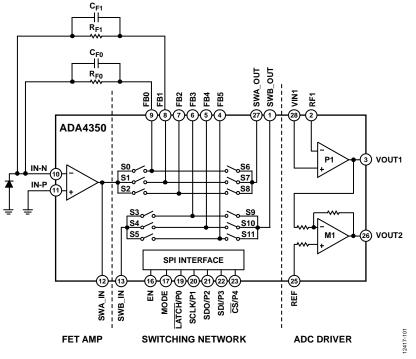


Figure 55. Simplified Schematic

| Bit No. | Function | Default Setting |
|-----------------|---|-----------------|
| 0 | S0 on/off control. Write 1 to this bit to close Switch S0. | 0 |
| 1 | S1 on/off control. Write 1 to this bit to close Switch S1. | 0 |
| 2 | S2 on/off control. Write 1 to this bit to close Switch S2. | 0 |
| 3 | S3 on/off control. Write 1 to this bit to close Switch S3. | 0 |
| 4 | S4 on/off control. Write 1 to this bit to close Switch S4. | 0 |
| 5 | S5 on/off control. Write 1 to this bit to close Switch S5. | 0 |
| 6 | S6 on/off control. Write 1 to this bit to close Switch S6. | 0 |
| 7 | S7 on/off control. Write 1 to this bit to close Switch S7. | 0 |
| 8 | S8 on/off control. Write 1 to this bit to close Switch S8. | 0 |
| 9 | S9 on/off control. Write 1 to this bit to close Switch S9. | 0 |
| 10 | S10 on/off control. Write 1 to this bit to close Switch S10. | 0 |
| 11 | S11 on/off control. Write 1 to this bit to close Switch S11. | 0 |
| 12 | Reserved. Set to logic low. | 0 |
| 13 ¹ | Optional internal 1 pF feedback capacitor between the inverting input and the output of the amplifier. Write 1 to this bit to turn the capacitor on. | 0 |
| 14 | Disable the SDO pin. Write 1 to this bit to disable the SDO pin. | 0 |
| 15 | Disable the M1 amplifier. Write 1 to this bit to disable the M1 amplifier. | 0 |
| 16 | Reserved. Set to logic low. | 0 |
| 17 | Reserved. Set to logic low. | 0 |
| 18 | Reserved. Set to logic low. | 0 |
| 19 | Reserved. Set to logic low. | 0 |
| 20 | Reserved. Set to logic low. | 0 |
| 21 | Reserved. Set to logic low. | 0 |
| 22 | Reserved. Set to logic low. | 0 |
| 23 | Read/write bit. Set to 1 to read and set to 0 to write. | 0 |

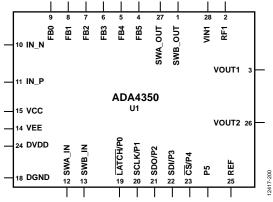
¹ The optional internal 1 pF feedback capacitor provides a quick and convenient way to compensate the TIA when using a high value feedback resistor (>1 MΩ).

Table 15. Serial Mode Operation

| Command (Hex Code Format, B23B0) | Switch Closed | Gain Path Selected |
|----------------------------------|---------------|--|
| 00 00 41(MSB Side) | S0 and S6 | FB0 |
| 00 20 41 | S0 and S6 | FB0, optional internal feedback capacitor on |
| 00 00 82 | S1 and S7 | FB1 |
| 00 01 04 | S2 and S8 | FB2 |
| 00 02 08 | S3 and S9 | FB3 |
| 00 04 10 | S4 and S10 | FB4 |
| 00 08 20 | S5 and S11 | FB5 |

SPICE MODEL

The SPICE model only supports parallel mode operation. Pin P5 enables parallel mode and allows full switching network functionality. The EN and MODE inputs are internally set to high and low, respectively, and are not accessible in this model. Figure 56 shows the recommended symbol pins when creating the ADA4350 symbol in the SPICE simulator.





| Symbol Pin | Model Node | Pin No. | Mnemonic |
|------------|------------|----------------|----------|
| 1 | N10 | 10 | IN_N |
| 2 | N11 | 11 | IN_P |
| 3 | VCC | 15 | VCC |
| 4 | VEE | 14 | VEE |
| 5 | VDD | 24 | DVDD |
| 6 | DGND | 18 | DGND |
| 7 | N12 | 12 | SWA_IN |
| 8 | N13 | 13 | SWB_IN |
| 9 | PO | 19 | LATCH/P0 |
| 10 | P1 | 20 | SCLK/P1 |
| 11 | P2 | 21 | SDO/P2 |
| 12 | P3 | 22 | SDI/P3 |
| 13 | P4 | 23 | CS/P4 |
| 14 | P5 | Not applicable | P5 |
| 15 | N25 | 25 | REF |
| 16 | N26 | 26 | VOUT2 |
| 17 | N3 | 3 | VOUT1 |
| 18 | N2 | 2 | RF1 |
| 19 | N28 | 28 | VIN1 |
| 20 | 27 | 27 | SWA_OUT |
| 21 | 1 | 1 | SWB_OUT |
| 22 | 4 | 4 | FB5 |
| 23 | 5 | 5 | FB4 |
| 24 | 6 | 6 | FB3 |
| 25 | 7 | 7 | FB2 |
| 26 | 8 | 8 | FB1 |
| 27 | 9 | 9 | FBO |

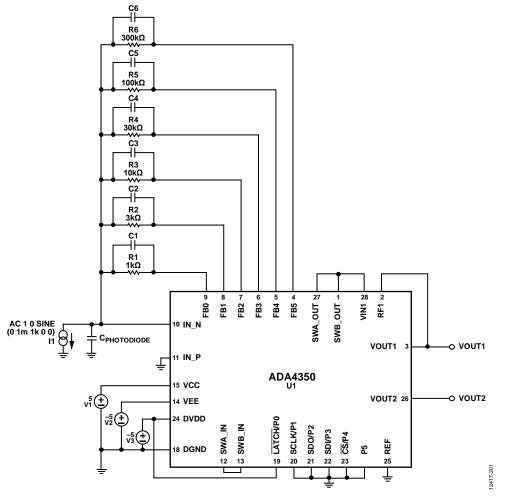


Figure 57. SPICE Schematic Example to Test Basic Functionality

TRANSIMPEDANCE AMPLIFIER DESIGN THEORY

Because its low input bias current minimizes the dc error at the preamp output, the ADA4350 works well in photodiode preamp applications. In addition, its high gain bandwidth product and low input capacitance maximizes the signal bandwidth of the photodiode preamp. Figure 58 shows the transimpedance amplifier model of the ADA4350.

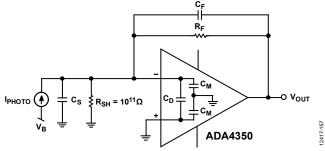


Figure 58. Transimpedance Amplifier Model of the ADA4350

The basic transfer function in Equation 4 describes the transimpedance gain of the photodiode preamp.

$$V_{OUT} = \frac{I_{PHOTO} \times R_F}{1 + sC_F R_F} \tag{4}$$

where:

*I*_{PHOTO} is the output current of the photodiode.

 R_F is the feedback resistor.

 C_F is the feedback capacitance.

The signal bandwidth is $1/(R_F \times C_F)$, as determined by Equation 4. In general, set R_F such that the maximum attainable output voltage corresponds to the maximum diode current, I_{PHOTO} , allowing the use of the full output swing.

The signal bandwidth attainable with this preamp is a function of R_F , the gain bandwidth product (f_{GBW}) of the amplifier, and the total capacitance at the amplifier summing junction, including C_S and the amplifier input capacitance of C_D and C_M . R_F and the total capacitance produce a pole with the loop frequency (f_P).

$$f_P = 1/2\pi R_F C_S \tag{5}$$

With the additional pole from the open-loop response of the amplifier, the two-pole system results in peaking and instability due to an insufficient phase margin (see gray lines for the noise gain and phase in Figure 59).

Adding C_F to the feedback loop creates a zero in the loop transmission that compensates for the effect of the input pole, which stabilizes the photodiode preamp design because of the increased phase margin (see the gray lines for the noise gain and phase in Figure 60). It also sets the signal bandwidth, fz (see the I to V gain line for the signal gain in Figure 60). The signal bandwidth and the zero frequency, fz, are determined by

$$f_z = \frac{1}{2\pi R_F C_F} \tag{6}$$

Equating the zero frequency, f_Z , with the f_X frequency maximizes the signal bandwidth with a 45° phase margin. Calculate f_X as follows because f_X is the geometric mean of f_P and f_{GBW} :

$$f_x = \sqrt{f_P \times f_{GBW}} \tag{7}$$

By combining Equation 5, Equation 6, and Equation 7, the $C_{\rm F}$ value that produces $f_{\rm X}$ is defined by

$$C_F = \sqrt{\frac{C_S}{2\pi \times R_F \times f_{GBW}}}$$
(8)

The frequency response in this case shows approximately 2 dB peaking and 15% overshoot. Doubling C_F and cutting the bandwidth in half results in a flat frequency response with approximately 5% transient overshoot.

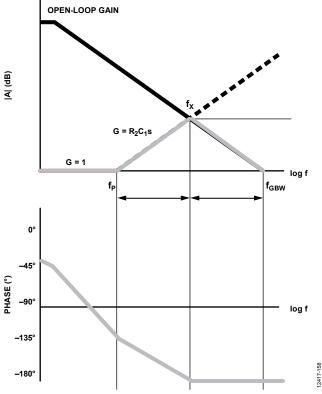


Figure 59. Noise Gain and Phase Bode Plot of the Transimpedance Amplifier Design Without Compensation

Data Sheet

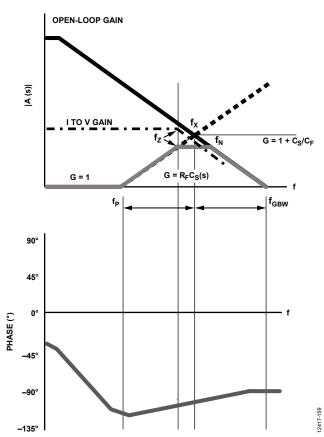


Figure 60. Signal and Noise Gain and Phase of the Transimpedance Amplifier Design with Compensation

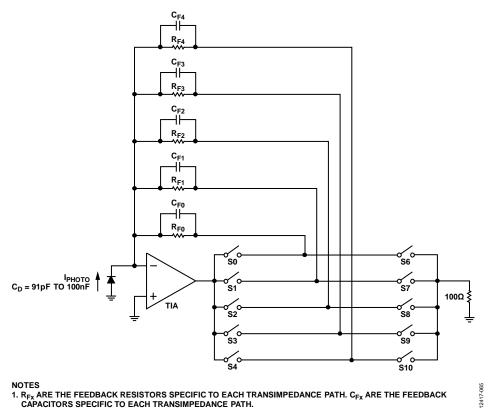
The dominant output noise sources in the transimpedance amplifier design are the input voltage noise of the amplifier, V_{NOISE} , and the resistor noise due to R_{F} . The effect due to the current noise is negligible in comparison. The gray line in Figure 60 shows the noise gain and phase over frequencies for the transimpedance amplifier. The noise bandwidth is at the f_{N} frequency, and is calculated by

$$f_N = \frac{f_{GBW}}{(C_s + C_F)/C_F} \tag{9}$$

Table 17 shows the dominant noise sources (R_F and V_{NOISE}) for the transimpedance amplifier when it has a 45° phase margin for the maximum bandwidth, and in this case, $f_Z = f_X = f_N$.

| Table 17. RMS Noise Contributions of Transimpedance | |
|---|--|
| Amplifier | |

| Contributor | Expression |
|--------------------|---|
| R _F | $\sqrt{4kT \times R_F \times f_N \times \frac{\pi}{2}}$ |
| V _{NOISE} | $V_{\text{NOISE}} \times \frac{\left(C_{\text{S}} + C_{M} + C_{F} + 2C_{D}\right)}{C_{F}} \times \sqrt{\frac{\pi}{2} \times f_{N}}$ |





TRANSIMPEDANCE GAIN AMPLIFIER PERFORMANCE

Figure 61 shows the ADA4350 configured as a transimpedance amplifier with five different gains. The photodiode sensor capacitance, C_D , varies from 91 pF to 100 nF to showcase the transimpedance gain performance at various frequency. Figure 62 to Figure 65 shows the transimpedance vs. frequency at different C_D settings. Note that the compensation capacitors, C_{F0} to C_{F4} , correct for the inherent instability of the transimpedance configuration. Capacitors chosen were such that the transimpedance gain response compensates for the maximum bandwidth and is close to having a 45° phase margin.

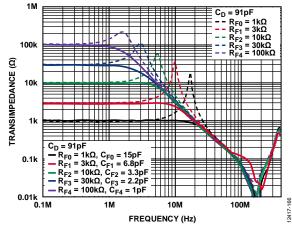


Figure 62. Transimpedance vs. Frequency, $C_D = 91 \, pF$

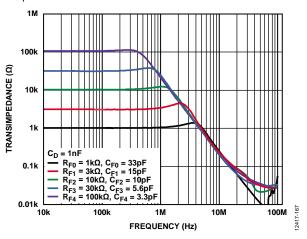
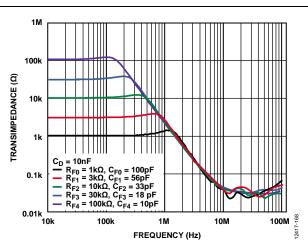
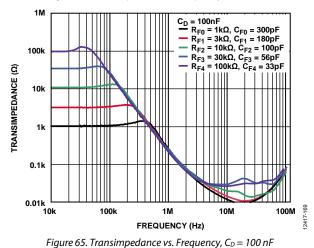


Figure 63. Transimpedance vs. Frequency, $C_D = 1 \text{ nF}$



Data Sheet

Figure 64. Transimpedance vs. Frequency, $C_D = 10 \text{ nF}$



THE EFFECT OF LOW FEEDBACK RESISTOR R_{Fx}

As the load of the transimpedance amplifier increases, excessive peaking in the frequency response can be observed when the R_{Fx} value is too small. This peaking can persist even when excessive C_{Fx} overcompensates for it. Figure 66 shows the ADA4350 configured with a photodiode capacitance value of 91 pF and a 1 k Ω transimpedance load. Figure 67 shows the normalized frequency response of this configuration. By decreasing R_F from 500 Ω to 68 Ω , the peaking in the frequency response increases progressively. The large peaking translates to a huge overshoot in the pulse response, which is an undesirable result.

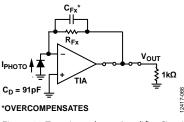


Figure 66. Transimpedance Amplifier Circuit

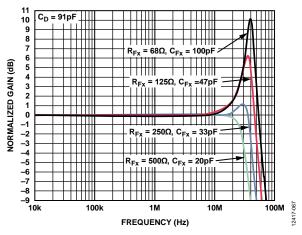


Figure 67. Normalized Frequency Response with Decreasing R_F (See Figure 66)

To mitigate this effect, use an additional snubber circuit at the output of the FET input amplifier, as shown in Figure 68. In this configuration, the feedback resistor (R_{Fx}) is 68 Ω , and the capacitance of the photodiode is 40 pF.

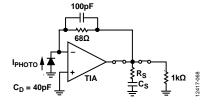


Figure 68. Snubber Circuit Added to Mitigate Peaking

Figure 69 shows the effect of various snubber circuits clamping down the peaking. Without the snubber circuit, there is 6 dB of peaking when an overcompensated C_{Fx} of 100 pF is used. With the snubber circuits, the bandwidth is restricted to approximately 10 MHz. To compromise between the peaking and the bandwidth, adjust the values of the snubber circuit.

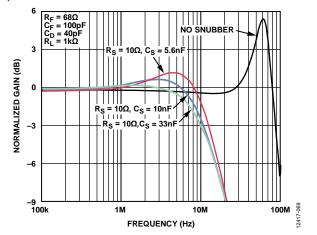


Figure 69. Effect of Snubber Circuits on the Transimpedance Frequency Response (See Figure 68)

USING THE T NETWORK TO IMPLEMENT LARGE FEEDBACK RESISTOR VALUES

Large feedback resistors (>1 $M\Omega$) can cause the two following issues in the transimpedance amplifier design:

- If the parasitic capacitance of the feedback resistor exceeds the optimal compensation value, it can significantly reduce the TIA signal bandwidth.
- If the required compensation capacitance is too low (<1 pF), it is not practical to choose a feedback capacitor.

The T network (the R_{Fx} , R2, and R1 resistors) maintains the transimpedance gain and signal bandwidth with a lower feedback resistor and a resistive gain network, as shown in Figure 70.

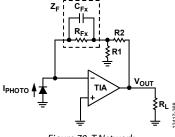


Figure 70. T Network

The relationship between the transimpedance V_{OUT}/I_{PHOTO} and the T network resistors (R_{Fx} , R1, and R2) can be expressed as

$$\frac{V_{OUT}}{I_{PHOTO}} = -Z_F \times \left(1 + \frac{R2}{R1} + \frac{R2}{Z_F}\right)$$
(10)

where:

 V_{OUT} is the output voltage of the TIA.

*I*_{PHOTO} is the input photodiode current.

 $Z_F = R_{Ex}/((R_{Ex} \times C_{Ex})s + 1)$, where R_{Ex} and C_{Ex} are the feedback resistor and capacitor, respectively, of any of the chosen transimpedance gain paths. *R1* and *R2* are the T network gain resistors.

If $Z_F >> R2$, the transimpedance equation is simplified to

$$\frac{V_{OUT}}{I_{PHOTO}} = -\frac{R_{F_x}}{(R_{F_x} \times C_{F_x})s + 1} \times \left(1 + \frac{R^2}{R^2}\right)$$

Therefore, as compared to the standard TIA design, the T network uses a feedback resistor value that is 1/(1 + R1/R2) smaller to obtain the same transimpedance. This eliminates the concern of the high parasitic capacitance associated with the large feedback resistor. To maintain the same signal bandwidth (or same pole), increase C_F by a factor of 1 + R2/R1 to eliminate concerns of an impractical small compensation capacitor.

As compared to a standard TIA design, the T network is noisier because the dominant voltage noise density is amplified by the gain factor 1 + R2/R1.

Figure 71 shows the ADA4350 configured as a 1 M Ω transimpedance path and its T network equivalent. Figure 72 compares the performance of the 1 M Ω path and the equivalent T network with and without compensation capacitors.

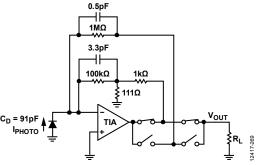


Figure 71. 1 M Ω Transimpedance Path and its Equivalent T Network

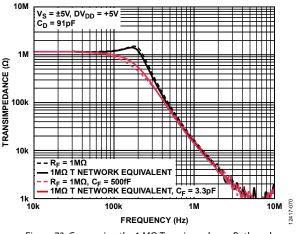
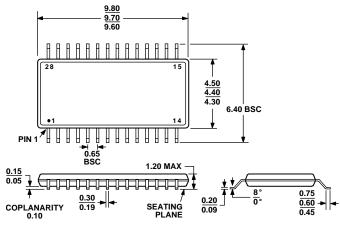


Figure 72. Comparing the 1 $M\Omega$ Transimpedance Path and T Network Performance

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-153-AE

Figure 73. 28-Lead Thin Shrink Small Outline Package [TSSOP], (RU-28) Dimensions shown in millimeters

ORDERING GUIDE

| Model ¹ | Temperature Range | Package Description | Package Option |
|--------------------|-------------------|--|----------------|
| ADA4350ARUZ | -40°C to +85°C | 28-Lead Thin Shrink Small Outline Package [TSSOP] | RU-28 |
| ADA4350ARUZ-R7 | -40°C to +85°C | 28-Lead Thin Shrink Small Outline Package [TSSOP] | RU-28 |
| EVAL-ADA4350RUZ-P | | Evaluation Board for 28-Lead TSSOP, Precision Version with Guard Rings | |

¹ Z = RoHS Compliant Part.

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Rev. B | Page 37 of 37